



Cryogenic BLMs for the LHC

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Outline

- Motivation
- Investigated detectors
- Beam test measurement setup
- Results
 - Semiconductors
 - Liquid helium chamber
- Conclusions and outlook





Limit close to interaction regions

Problem: in triplet magnets signal from debris with similar height as simulated beam losses in steady state case







Cryogenic BLM as solution

- Future BLMs placed closer to:
 - where losses happen and
 - the element needing protection (so inside cold mass of the magnet, 1.9 K)
- Measured dose then better corresponds to dose inside the coil







Investigated detectors

Silicon

 Successfully used at 1 K at CERN in 1976 -""Frozen Spin" Polarized Target"

Diamond

- Successfully in use as LHC BLM at room temperature
- Radiation harder than Si at room temperature (high displacement energy 43 eV)
- Less leakage current than Si at room temperature (high band gap of 5.48 eV)
- Low dielectric constant
- Liquid helium ionisation chamber
 - + No radiation hardness issue
 - Slow (charge mobility of 0.02 cm²/V/s)









Signal from LHC Diamond BLM







CERN PS Beam test area







Setups used

In liquid helium



At room temperature



Semiconductors:

Silicon p⁺-n-n⁺ with 300 μm thickness and single crystal chemical vapor deposition (CVD) **Diamond** with 500 μm thickness

LHe chamber

3.9 cm active length

With Erich Griesmayer and Christina Weiss









Cable length between detectors and preamplifiers ~ 2 m

Due to long cables advantage of low noise at LHe temperatures is partly lost.





Beam characteristics

- Particles consist of protons (dominating), positive pions and kaons
- 9 GeV/c particles -> MIPs
- Beam intensity **350 000 particles/spill**
- Size at focus about 1 cm²
- Spill duration of 400 ms (less than 1 particle/µs)
- One spill every 45 s







40 dB current amplifier from CIVIDEC, bandwidth 1 MHz – 2 GHz



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Silicon results Single particle (response averaged from ~5000 pulses)





Drift time change at liquid helium temperatures of 54% Additionally: leakage current below pA at liquid helium temperature

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Silicon 680 nm laser measurement

Transient current technique measurements: laser applied on one side of Silicon. Charges travel through bulk, giving information about their characteristics.



Temperature scan



Diamond results Single particle (response averaged from ~5000 pulses)



Drift time change of about 28%







Liquid helium chamber

Intensity variation



Linearity is observed in the range from 5 to 140 pC

Voltage variation



Full charge collection not reached at an electric field of 3.33 kV/cm

Charge collection time in the order of several 100 μ s, only interesting for steady state losses

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Radiation hardness – Room temperature





Main disadvantage of Si is its leakage current (45 μ A at 100 V and a fluency of 1e15 p/cm²). In cold Si leakage current expected to stay below pA. Radiation hardness tests repeated in cold in November.







First cryogenic LHC detectors



Technical drawing Thierry Renaglia

Installation of 2 Silicon and 2 Diamond detectors in Q7 at 1.9 K planed for October 2012.





Conclusions

- All tested **detectors work** at superfluid helium temperatures:
 - Reduction of the drift time by 28 % for Diamond and 54 % for Silicon
 - Reduction of Silicon dark current from 5 nA at 100V at room temperature to below pA at 2 K
- With semiconductors a fast detection system for bunch by bunch resolution in the LHC and DC measurements for steady state losses possible
- Liquid helium chamber elegant solution as CryoBLM in the triplet magnets - no issues with radiation hardness
- Ongoing tests and data analysis







- CERN Cryogenic team,
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